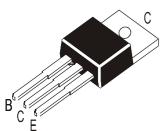




PLASTIC POWER TRANSISTORS

TIP31, A, B, C NPN TIP32, A, B, C PNP

> TO-220 Plastic Package



Complementary Silicon Transistors intended for a wide variety of Switching and Amplifier Applications, Series and Shunt Regulators, Driver and Output stages of Hi-Fi Amplifiers

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

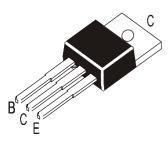
DESCRIPTION	SYMBOL	TIP31	TIP31A	TIP31B	TIP31C	UNIT
		TIP32	TIP32A	TIP32B	TIP32C	
Collector Emitter Voltage	V _{CEO}	40	60	80	100	V
Collector Base Voltage	V _{CBO}	40	60	80	100	V
Emitter Base Voltage	V _{EBO}	5				V
Collector Current Continuous	I _C	3				А
Collector Current Peak	I _{CM}	5				А
Base Current	I _B	1				Α
Power Dissipation upto T _c =25 ^e C	PD	40				W
Derate above 25ºC		320				mW/ºC
Power Dissipation upto T _a =25 ^o C	PD	2				W
Derate above 25ºC		16				mW/ºC
Unclamped Inductive Load Energy	*E	32				mJ
Operating And Storage Junction Temperature	T _j , T _{stg}	- 65 to +150			°C	

THERMAL RESISTANCE

Junction to Case	R _{th (j-c)}	3.125	ºC/W
Junction to Ambient in free air	R _{th (j-a)}	62.5	°C/W

* I_c=1.8A, L=20mH, P.R.F.=10Hz, V_{cc}=10V, R_{BE}=100 Ω

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ELECTRICAL CHARACTERISTICS (T_c=25^oC unless specified otherwise)

SYMBOL	TEST CONDITION	MIN	MAX	UNIT	
*V _{CEO(sus)}	I _C =30mA, I _B =0				
	TIP31/32	40		V	
	TIP31A/32A	60		V	
	TIP31B/32B	80		V	
	TIP31C/32C	100		V	
I _{CEO}	V_{CE} =30V, I _B =0				
	TIP31, A / 32, A		0.3	mA	
	V_{CE} =60V, I_{B} =0				
	TIP31B, C / 32B, C		0.3	mA	
I _{CES}	$V_{CE} = V_{CEO}(max), V_{BE} = 0$	V _{BE} =0 0.2		mA	
I _{EBO}	$V_{EB}=5V, I_{C}=0$		1.0	mA	
*h _{FE}	$I_{C}=1A, V_{CE}=4V$	25			
	$I_{C}=3A, V_{CE}=4V$	10	50		
*V _{CE(sat)}	I _C =3A, I _B =375mA		1.2	V	
*V _{BE(on)}	I _C =3A, V _{CE} =4V		1.8	V	
	*V _{CEO(sus)} I _{CEO} I _{CES} I _{EBO} *h _{FE} *V _{CE(sat)}	$\begin{tabular}{ c c c c c c c } & I_{C}=30mA, I_{B}=0 & $$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$	$\begin{tabular}{ c c c c c c c } \hline & & & & & & & & & & & & & & & & & & $		

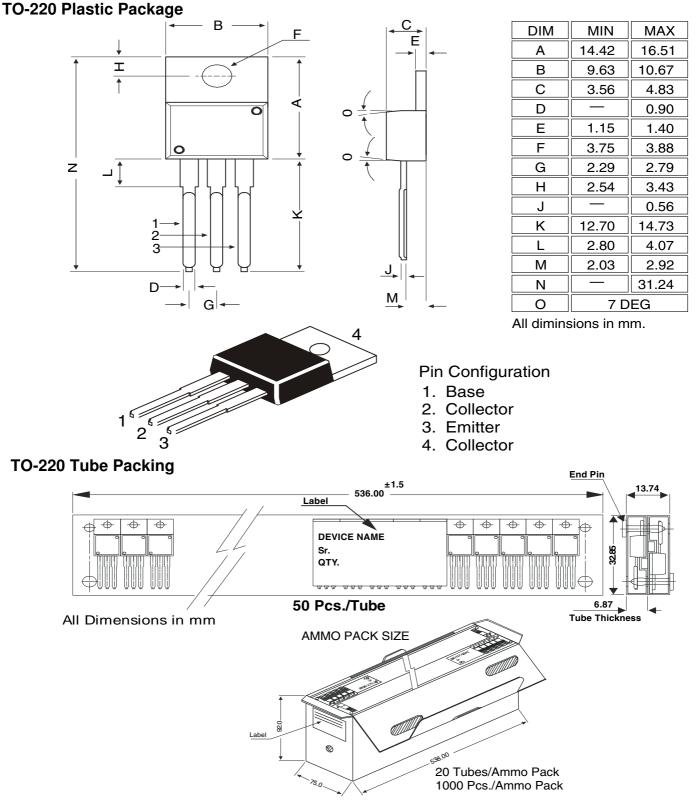
*Pulse Test : Pulse width \leq 300 μ s, Duty Cycle \leq 2%

DYNAMIC CHARACTERISTIC

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Small Signal Current Gain	h _{fe}	$I_C=0.5A$, $V_{CE}=10V$, f=1KHz	20		
Transition Frequency	f _T	$I_C=0.5A$, $V_{CE}=10V$, f=1MHz	3		MHz

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Packing Detail

PACKAGE	STANDA	ARD PACK	INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-220 / FP	200 pcs/polybag 50 pcs/tube	396 gm/200 pcs 120 gm/50 pcs	3" x 7.5" x 7.5" 3.5" x 3.7" x 21.5"	1.0K 1.0K	17" x 15" x 13.5" 19" x 19" x 19"	16.0K 10.0K	36 kgs 29 kgs

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Disclaimer

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